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February 2017



FFPF60SA60DS 8 A, 600 V, STEALTHTM Dual Series Diode

Features

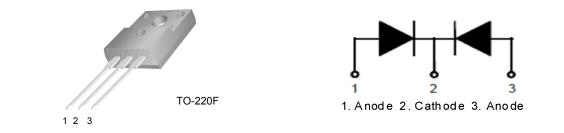
- Stealth Recovery t_{rr} = 39 ns (@ I_F = 8 A)
- Max Forward Voltage, V_F = 2.4 V (@ T_C = 25°C)
- · 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- · RoHS Compliant

Applications

- · SMPS FWD, Motor Drive FWD, Snubber Diode
- Hard Switched PFC Boost Diode
- · UPS FWD

Description

The FFPF60SA60DS is STEALTH™ dual series diode with soft recovery characteristics. It is silicon nitride passivated ionimplanted epitaxial planar construction. This device is intended for use as freewheeling of boost diode in switching power supplies and other power swithching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.



Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Rating	Unit	
V _{RRM}	Peak Repetitive Reverse Voltage	600	V	
V _{RWM}	Working Peak Reverse Voltage	600	V	
V _R	DC Blocking Voltage	600	V	
I _{F(AV)}	Average Rectified Forward Current $@T_{C} = 95^{\circ}C$	8	Α	
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	80	А	
P _D	Power Dissipation	26	W	
W _{AVL}	Avalanche Energy (1 A, 40 mH)	20	mJ	
T _J , T _{STG}	Operating Junction and Storage Temperature	-65 to +175	°C	

Thermal Characteristics

Symbol	Parameter	Max.	Unit
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	3.125	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	62.5	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFPF60SA60DSTU	FFPF60SA60DS	TO-220F	Tube	N/A	N/A	30

Symbol	Parameter	Min.	Тур.	Max.	Unit	
	Forward Voltage I _F = 8 A I _F = 8 A	T _C = 25°C T _C = 125°C	-	2.0 1.6	2.4 2.0	V
I _R 1	Reverse Current @rated V _R	T _C = 25°C T _C = 125°C	-	-	100 1000	μA
t _{rr}	Maximum Reverse Recovery Time ($I_F = 1 \text{ A}, \text{ di}_F/\text{dt} = 100 \text{ A}/\mu\text{s}, \text{V}_R = 30 \text{ V}$)		-	-	25	ns
t _{rr}	Maximum Reverse Recovery Time ($I_F = 8 \text{ A}, \text{ di}_F/\text{dt} = 100 \text{ A}/\mu\text{s}, \text{V}_R = 30 \text{ V}$)		-	-	30	ns
t _{rr} I _{rr} Q _{rr}	Reverse Recovery Time Reverse Recovery Current Reverse Recovery Charge (I _F = 8 A, di _F /dt = 200 A/µs, V _B = 390 V)			39 2 39		ns A nC

Notes:

1: Pulse: Test Pulse width = 300μ s, Duty Cycle = 2%

Test Circuit and Waveforms

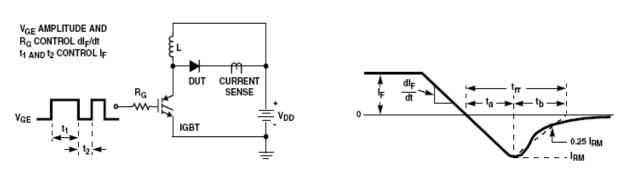


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

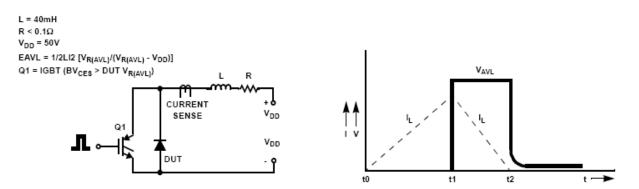
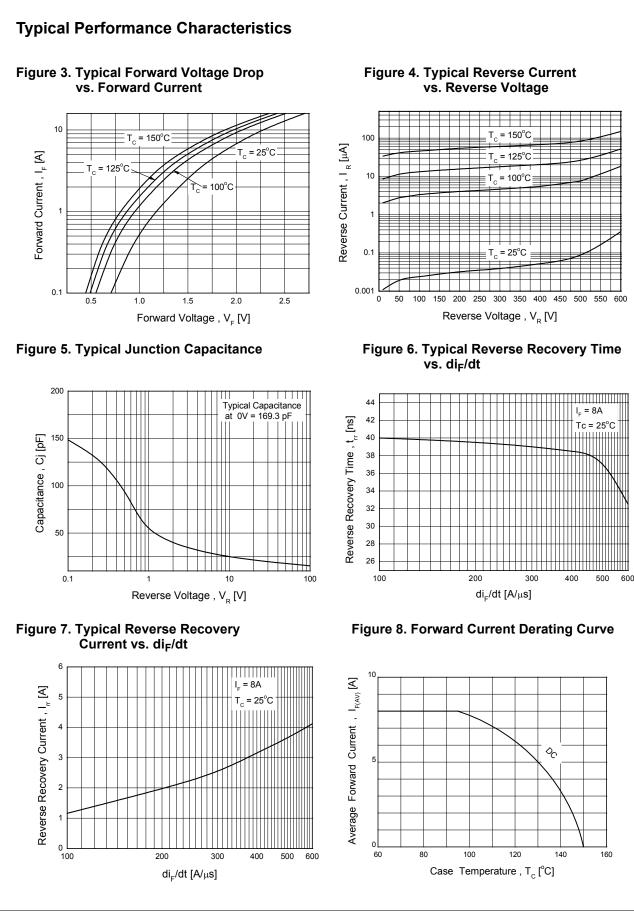
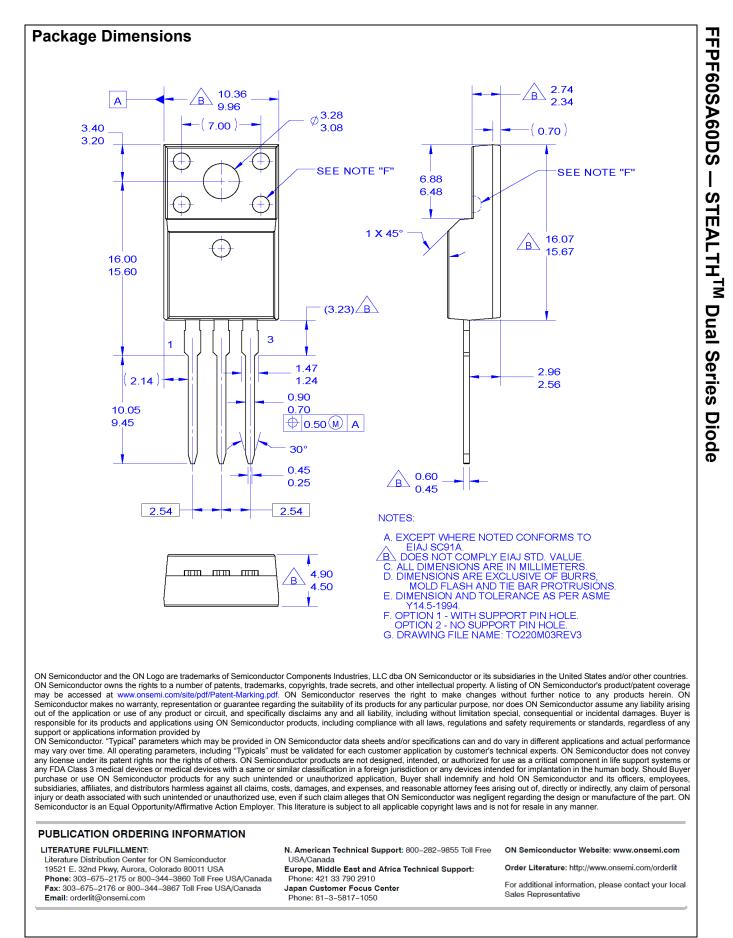


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform



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